

SANYO Semiconductors DATA SHEET

An ON Semiconductor Company

LV58063MC — Step-down Switching Regulator **Bi-CMOS LSI**

Overview

LV58063MC is a 1ch step-down switching regulator. 0.13Ω FET is incorporated on the upper side to achieve high-efficiency operation for large output current.

Low-heat resistance and compact-package SOP8L (200mil) employed.

Current mode control gives superior load current response with easy phase compensation.

EN pin, allowing the standby mode with the current drain of 70μA.

Pulse-by-pulse over-current protection and overheat protection available for protection of load devices.

Externally adjustable soft start time.

Features

- 3A 1ch step-down switching regulator
- Wide input range (8 to 28V)
- High efficiency (90% IOUT=1A, VIN=12V, VOUT=5V) Fixed frequency: 370kHz
- Standby mode
- Over-current protection
- Overshoot control after over-current protection event
- Thermal shutdown
- Reference voltage: 0.8V
- Soft start
- Compact package: SOP8L (200mil) with exposed pad

Application

• LCD/PDP-TV STB White Goods Office equipment

General consumer electronics

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Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Conditions	Conditions	Ratings	Unit
Maximum input V _{IN} voltage	V _{IN} max		32	V
BOOT pin maximum voltage	V _{BT} max		37	V
SW pin maximum voltage	V _{SW} max		V _{IN} max	V
BOOT pin-SW pin maximum voltage	V _{BS-SW} max		7	V
FB, EN, COMP, SS pin maximum	Vfs max		7	V
voltage				
Allowable power dissipation	Pd max	Mount on a specified board *	2.05	W
Junction temperature	Tj max		150	°C
Operating temperature	Topr		-20 to +80	°C
Storage temperature	Tstg		-40 to +150	°C

^{*} Specified board: 46.4mm \times 31.8mm \times 1.7mm, glass epoxy.

Note: Plan the maximum voltage while including coil and surge voltages, so that the maximum voltage is not exceeded even for an instant.

Recommended Operating Conditions at Ta = 25°C

Parameter	Conditions	Conditions	Ratings	Unit
V _{IN} pin voltage	V _{IN}		8 to 28	V
BOOT pin voltage	V _{BT}		-0.3 to 34	V
SW pin voltage	V _{SW}		-0.4 to V _{IN}	V
BOOT pin-SW pin voltage	V _{BS-SW}		6.5	V
FB, EN, COMP, SS pin voltage	V _{FSO}		6	V

Electrical Characteristics at Ta = 25 °C $V_{\mbox{IN}} = 12V$, unless otherwise specified.

Devenuetes	Conditions	Conditions		Ratings		
Parameter	Conditions		min	typ	max	Unit
IC current drain at standby	I _{CC} 1	EN=0V		70		μΑ
IC current drain in operation	I _{CC} 2	EN=open, FB=1V		5		mA
Efficiency	Effcy	V _{IN} =12V, I _{OUT} =1A, V _O =5V Design target: *1		90		%
Reference voltage	Vref	V _{IN} =8V to 28V (±2%)	-2%	0.8	+2%	V
FB pin bias current	Iref	FB=0.8V application		10	100	nA
High-side ON resistance	RonH	BOOT=5V		0.13		Ω
Low-side ON resistance	RonL			7		Ω
Oscillation frequency	Fosc		296	370	444	kHz
Oscillation frequency during short-circuit protection	Foscs		30	38	46	kHz
EN high-threshold voltage	Venh				1.9	V
EN low-threshold voltage	VenI		0.8			V
EN pull-up corrent	len	EN=0V		16		μΑ
Maximum ON DUTY	D max			80		%
Current limit peak value 1	Icl1	V _{IN} =12V, V _{OUT} =5V, L=10μH	3.8			Α
Thermal shutdown temperature	Ttsd	*Design guarantee *2		160		°C
Thermal shutdown temperature hysteresis	Dtsd	*Design guarantee *2		40		°C
Soft start current	I _{SS}	SS=0V	6	10	14	μΑ

^{*1:} Reference value (not tested before shipment)

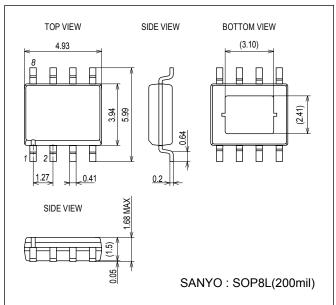
^{*2:} Design guarantee (value guaranteed by design and not tested before shipment)

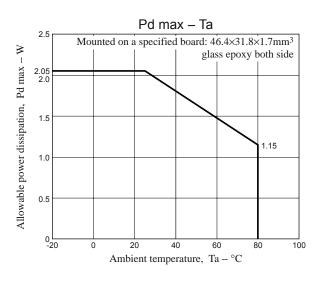
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Package Dimensions

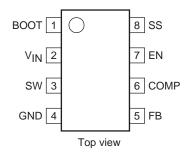
unit: mm (typ)

3439

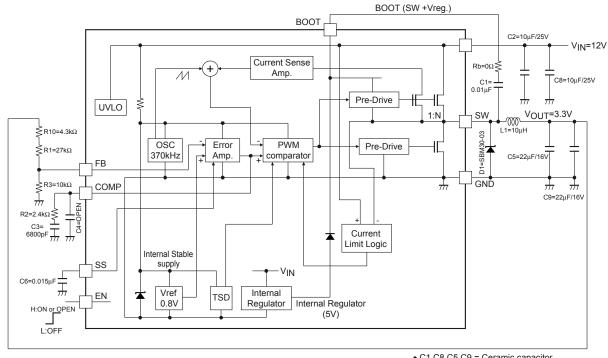




Pin Assignment



Block Diagram and Sample Application Circuit (3.3V output)



- C1,C8,C5,C9 = Ceramic capacitor L1=CDRH105RNP-100NC (sumida)

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Pin Function

Pin No.	Pin name	Description	Equivalent Circuit
1	воот	Internal high side nmos fet boot strap capacitor terminal. Connect around 22nF capacitor or greater between SW and BOOT. To operate within absolute maximum rating of SW, to keep stable operation, and to reduce switching noise, please, use a series resistor, Rb (value is around 100Ω) is recommended to use.	CBOOT Hi side MOS SW Low side MOS
2	V _{IN}	Input Voltage Pin. Large Filter Capacitor (equal or larger than 20μF) should be connected between V _{IN} and GND to eliminate noise on the input and to operate properly.	See BOOT
3	SW	Power Switching Pin. Connect the output LC filter. Connect the above-mentioned capacitor between this pin and BOOT pin.	See BOOT
4	GND	Ground pin.	
5	FB	Feedback pin. Connect a voltage divider resistor across FB to set the regulated output voltage. The output voltage is given by next equation. $V_{OUT} = Vref \times \left\{1 + \frac{(R1 + R10)}{R3}\right\}$ $Vref = 0.8V$ Example: 3.3V output voltage (See Block Diagram and Sample Application Circuit) $V_{OUT} = 0.8 \times \left\{1 + \frac{(27k + 4.3k)}{10k}\right\}$ =3.304V	VIN Internal regulated 10μΑ FB NREF N
6	COMP	Phase compensation pin. Connect an external capacitor and a resistor for the DC DC converter close loop-phase compensation.	COMP Clump circuit
7	EN	Enable terminal. If applying logically high voltage, or left open, the converter operates. If connected to GND, the converter's operation stops.	V _{IN} 1kΩ 274.5kΩ 186kΩ 93kΩ 2pF

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Pin No.	Pin name	Description	Equivalent Circuit
8	SS	Soft start terminal Internal source current (10µA) and external capacitor will make soft start time.	See FB
		Soft start capacitor, C6 is given by next equation, $C6 = 10\mu A \times \frac{Tss}{Vref}$	
		Where, Tss: soft start time, Vref: reference voltage Example: soft start time = 1.2ms	
		$C6 = 10\mu A \times \frac{1.2ms}{0.8 \text{ V}} = 0.015\mu F$	

Considerations for the design

- Insertion of serial beads in the Schottky diode for removal of noise may cause generation of the negative voltage on SW pin deviating from the absolute maximum rating at the SW pin, resulting in failure of normal operation. Please, do not insert beads as above described. Instead, remove noise by Rb resistor.
- Exposed pad on the bottom side of the IC should be soldered. We cannot recommend other usages of the exposed pad.

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